IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

pplicants:

Dean et al. 09/942451

Group Art Unit: 2879 Examiner: S.Leurig

Application No.:
Date Filed:

Title:

29 August 2001

TRIC.		EMISSION DISPI		ETHODS OF FORMING	A FIELD	
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I.	COPIES a. A legible copy of (i) each U.S. and foreign patents; (ii) each publication or that portion caused it to be listed; and (iii) all other information or that portion which caused it to be l					
	b.[enclosed herewith were	previously cited by		PTO/SB/08 which are not O in one of the following 35 U.S.C. §120:	
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ш	The Exa	to the present application	following co-pendin n. By bringing th	g application(s) contain(s)	subject matter that may be the Examiner's attention, 2.	
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<u>FEES</u>

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The above references are being cited only in the interests of candor and without any admission that they constitute statutory prior art or contain matter which anticipates the invention or which would render the same obvious, either singly or in a combination, to a person of ordinary skill in the art.

PATENT CR01-011

If the Examiner has any questions concerning this IDS, he/she is requested to contact the undersigned. If it is determined that this IDS has been filed under the wrong rule, the PTO is requested to consider this IDS under the proper rule (with a petition if necessary) and charge the appropriate fee to Deposit Account No. 502117

> Respectfully submitted, Dean et al.

MOTOROLA, INC. Customer Number 23330

William E. Koch Attorney for Applicant(s) Reg. No. 29,659 Tel. 602-952-3486

Enclosures:

PTO/SB/08 References

Foreign Search Report

Other:



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Substitute for form				Complete if Known				
				Application Number	09/942451			
INFORMATION	ON DISCLOSU	RE		Filing Date	August 29, 2001			
STATEMENT BY APPLICANT (use as many sheets as necessary)				First Named Inventor	Dean et al.			
				Group Art Unit				
				Examiner Name				
Sheet	1	of	4	Attorney Docket Number	CR01-011			

Examiner	Cite No.	U.S. Patent Docum		U. S. PATENT DOCUMENTS Name of Patentee or Applicant	Date of Publication of	Pages, Columns, Lines, Where
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	1	5872422		Xu et al.	2/16/99	
	2	5773921		Keesmann et al.	6/30/98	
	3	6514113 B1		Lee et al.	2/4/03	
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Substitute 1	for form 1449A/PTC)		Complete if Known		
		•		Application Number	09/942451	
INFORM	MATION DISC	LOSURE		Filing Date	August 29, 2001	
STATE	MENT BY APP	LICANT		First Named Inventor	Dean et al.	
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Sheet	2	Of	4	Attorney Docket Number	CR01-011	

Examiner	Cite	OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book,	T
Initials*	No. 1	magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	Ž
	4	Xu et al., "A method for fabricating large-area, patterned, carbon nanotube field emitters," Applied Physics Letters, Vol. 74, No. 17, 26 April 1999, pp. 2549-2551.	
, , , , , , , , , , , , , , , , , , , ,	5	Fan et al., "Self-oriented regular arrays of carbon nanotubes and their field emission properties," Science, Vol. 283, 22 January 1999, pp. 512-514.	
	6	Suh et al, "Highly ordered two-dimensional carbon nanotube arrays," Applied Physics Letters, Vol. 75, No. 14, 4 October 1999, pp. 2047-2049.	
· ·	7	Hernadi et al. "Catalytic synthesis of carbon nanotubes using zeolite support," Zeolites 17, 1996, pp. 416-423.	
	8	Murakami et al., "Field emission from well-aligned, patterned, carbon nanotube emitters," Applied Physics Letters, Vol. 76, No. 13, 27 March 2000, pp. 1776-1778.	
<u></u>	9	Ma et al., "Polymerized carbon nanobells and their field-emission properties," Applied Physics Letters, Vol. 75, No. 20, 15 November 1999, pp. 3105-3107.	
	10	Li et al, "Highly-ordered carbon nanotube arrays for electronics applications," Applied Physics Letters, Vol. 75, No. 3, 19 July 1999, pp. 367-369.	
	11	Terrones et al., "Controlled production of aligned-nanotube bundles," Nature, Vol. 388, 3 July 1997, pp.52-55.	
	12	Xu et al., "Controlling growth and field emission property of aligned carbon nanotubes on porous silicon substrates," Applied Physics Letters, Vol. 75, No. 4, 26 July 1999, pp. 481-483.	<u> </u>
	13	Tsai et al., "Bias-enchanced nucleation and growth of the aligned carbon nanotubes with open ends under microwave plasma synthesis," Applied Physics Letters, Vol. 24, No. 23, 7 June 1999, pp. 3462-3464.	
	14	Kind et al., "Patterned films of nanotubes using microcontact printing of catalysts," Advanced Materials, 11, No. 15, 1999, pp. 1285-1289.	

Examiner	Date
Signature	Considered



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INFORMATION DISCLOSURE STATEMENT BY APPLICANT				Filing Date	August 29, 2001		
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		OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS	
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	15	Nilsson et al., "Scanning field emission from patterned carbon nanotube films." Applied Physics Letters, Vol. 76. No. 15, 10 April 2000, pp. 2071-2073.	
	ļ		
	16	Kuttel et al, "Electron field emission from phase pure nanotube films grown in a methane/hydrogen plasma," Applied Physics Letters, Vol. 73, No. 15, 12 October 1998, pp. 2113-2115.	
	17	Ren et al., "Synthesis of large arrays of well-aligned carbon nanotubes on glass," Science, Vol. 282 6 November 1998, pp. 1105-1107.	
	18	Ren et al. "Growth of a single freestanding multiwall carbon nanotube on each nanonickel dot," Applied Physics Letters, Vol 75, No. 8 23 August 1999, pp. 1086-1088.	
	19	Pan et al., "Very long carbon nanotubes," Nature, Vol. 394, 13 August 1998, pp. 631-632.	
	20	Zhang et al., "A flat panel display device fabricated by using carbon nanotubes cathode," IEEE, 2001, pp. 193-194.	
	21	Zhong et al., "Large-scale well aligned carbon nitride nanotube films: Low temperature growth and electron field emission," Journal of Applied Physics, Vol. 89, No. 11, 1 June 2001, pp. 5939-5943.	
	22	Kim et al., "Growth and field emission of carbon nanotubes on electroplated Ni catalyst coated on glass substrates," Journal of Applied Physics, Vol. 90, 1 September 2001, pp.2591-2594.	
	23	Gulyaev et al., "Field emitter arrays on nanotube carbon structure films," J. Vac.Sci. Technol. B 13(2), Mar/Apr 1995, pp. 435-436.	
3	24	Chernozatonskii, et al. "Nanotube carbon structure tips – a source of high field emission of electrons," Mat. Res.Soc. Symp. Proc., Vol. 359. 1995 Materials Research Society, pp. 99-104.	
-	25	Su et al., "A scalable CVD method for the synthesis of single-walled carbon nanotubes with high catalyst productivity," Chemical Physics Letters 322, (2000), pp 321-326.	

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Initials*	No. ¹	magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.					
	26	Li et al. "Large-scale synthesis of aligned carbon nanotubes," Science, Vol. 274, 6 December 1996, pp. 1701-1703					
	27	Cassell et al. "Large scale CVD synthesis of single-walled carbon nanotubes," J. Phys. Chem. B. 1999, 103, pp. 6484-6492.	T				
Cassell et al. "Directed growth of free-standing single walled carbon nanotubes," J. A 1999, 121, pp. 7975-7976.							
	29	Cassell et al, "Combinatorial optimization of heterogeneous catalysts used in the growth of carbon nanotubes," Langmuir 2001, 17, pp. 260-264.	T				
30		Li et al, "Large-scale synthesis of aligned carbon nanotubes," Science, Vol. 274, 6 December 1996, pp. 1701-1703.	ig				
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